CLAIMS

What is claimed is:

- 1 1. A method for fabricating a write pole tip for perpendicular recording, comprising:
- 2 A) fabricating the P1, coils and P2 flux shaping layer;
- B) depositing the P3 layer on said P2 flux shaping layer;
- depositing a CMP stop layer on said P3 layer;
- 5 D) depositing at least one sacrificial layer on said CMP stop layer;
- 6 E) shaping said P3 layer into P3 pole tip;
- 7 F) removing said at least one sacrificial layer to leave said P3 pole tip; and
- 8 G) encapsulating said P3 pole tip in a encapsulating material.
- 1 2. The method of claim 1, wherein:
- 2 said P3 layer material of B) is a material chosen from the group consisting of
- 3 CoFe, CoFeN, NiFe, CoFe alloys, CoFeN alloys, NiFe alloys, Cr, Al₂O₃, and Ru.
- 1 3. The method of claim 1, wherein:
- 2 said CMP stop layer material of C) is a material chosen from the group consisting
- of Al_2O_3 , Ta_2O_5 , SiO_xN_y , Al_2O_3 alloys, Ta_2O_5 alloys, SiO_xN_y alloys, and insulation
- 4 materials.

- 1 4. The method of claim 1, wherein:
- 2 said at least one sacrificial layer of D) comprises a sacrificial layer PS of
- 3 sacrificial material chosen from the group consisting of NiFe, NiP and plated materials
- 4 with high ion milling resistances.
- 1 5. The method of claim 4, wherein:
- 2 said at least one sacrificial layer of D) further comprises a seed layer of sacrificial
- 3 material.
- 1 6. The method of claim 5, wherein:
- 2 said PS layer is formed by creating a cavity surrounded by photo-resist material,
- 3 said cavity then being filled with sacrificial material.
- 1 7. The method of claim 1, wherein:
- 2 said shaping of said P3 layer of E) is done by ion milling.
- 1 8. The method of claim 7, wherein:
- 2 said ion milling is done to first produce a straight-sided structure, as said PS layer
- 3 masks said P3 pole tip, and then said CMP stop layer acts as a secondary mask as ion
- 4 milling is used to bevel the sides of said P3 pole tip.

- 1 9. The method of claim 8, wherein:
- 2 said beveled sides of said P3 pole tip are beveled to an angle with the range of 8
- 3 degrees to 15 degrees.
- 1 10. The method of claim 1, wherein:
- 2 said finished P3 pole tip has a width less than 200 nm.
- 1 11. The method of claim 1, wherein:
- 2 said removing of said at least one sacrificial layer of F) further comprises
- 3 removing said CMP stop layer.
- 1 12. The method of claim 11, wherein:
- 2 said removing of said CMP stop layer comprises using Chemical Mechanical
- 3 Polishing.
- 1 13. The method of claim 1, wherein:
- 2 said encapsulating material of G) comprises material matching that of said CMP
- 3 stop layer.
- 1 14. The method of claim 1, wherein:
- 2 said at least one sacrificial layer of D) comprises magnetic material; and
- 3 said removing said at least one sacrificial layer of F) requires that all of said
- 4 magnetic material of said at least one sacrificial layer be completely removed..